

LM494 Pulse Width Modulated Control Circuit

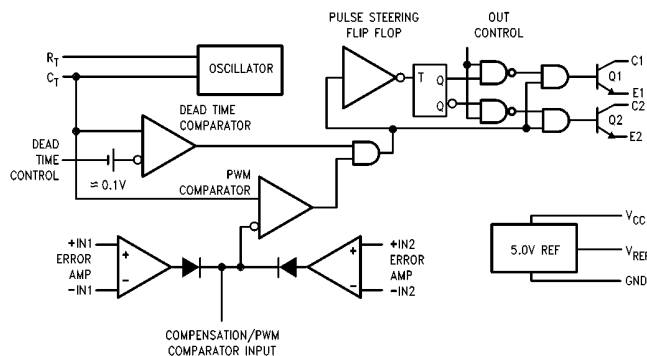
General Description

The LM494 is a monolithic integrated circuit which includes all the necessary building blocks for the design of pulse width modulated (PWM) switching power supplies, including push-pull, bridge and series configurations. The device can operate at switching frequencies between 1.0 kHz and 300 kHz and output voltages up to 40V. The operating temperature range specified for the LM494C is 0°C to 70°C and for the LM494V is -40°C to +85°C.

Features

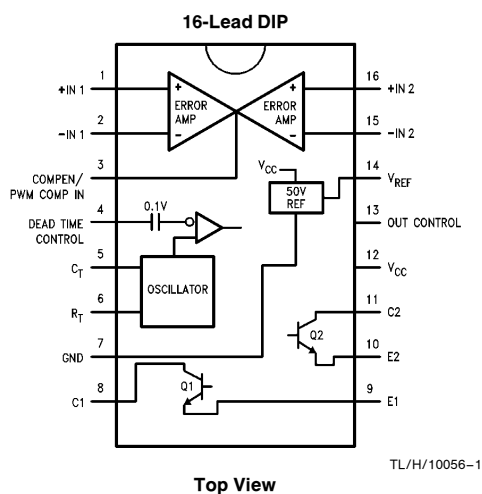
- Uncommitted output transistors capable of 200 mA source or sink
- On-chip error amplifiers
- On-chip 5.0V reference
- Internal protection from double pulsing of outputs with narrow pulse widths or with supply voltages below specified limits
- Dead time control comparator
- Output control selects single ended or push-pull operation
- Easily synchronized (slaved) to other circuits

Block Diagram



TL/H/10056-2

Connection Diagram



TL/H/10056-1

Ordering Information

| Device Code | Package Code | Package Description |
|-------------|--------------|---------------------|
| LM494IN | N16A | Molded DIP |
| LM494CJ | J16A | Ceramic DIP |
| LM494CN | N16A | Molded DIP |

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

| | |
|--|-----------------|
| Storage Temperature Range | |
| Ceramic DIP | −65°C to +175°C |
| Molded DIP | −65°C to +150°C |
| Operating Temperature Range | |
| Industrial (LM494I) | −40°C to +85°C |
| Commercial (LM494C) | 0°C to +70°C |
| Lead Temperature | |
| Ceramic DIP (Soldering, 60 sec.) | 300°C |
| Molded DIP (Soldering, 10 sec.) | 265°C |
| Internal Power Dissipation (Notes 1, 2) | |
| 16L-Ceramic DIP | 1.50W |
| 16L-Molded DIP | 1.04W |
| Supply Voltage | 42V |
| Voltage from Any Lead to Ground (except Lead 8 and Lead 11) | |
| | $V_{CC} + 0.3V$ |

| | |
|---|--------------------|
| Output Collector Voltage | 42V |
| Peak Collector Current (I_{C1} and I_{C2}) | 250 mA |
| ESD Susceptibility | (to be determined) |

Recommended Operating Conditions

| | |
|--|----------------------------------|
| Power Supply Voltage (V_{CC}) | 7.0V to 40V |
| Voltage on Any Lead except Leads 8 and 11 (Referenced to Ground) (V_I) | |
| | −0.3V to $V_{CC} + 0.3V$ |
| Output Voltage Collector (V_{C1}, V_{C2}) | −0.3V to 40V |
| Output Collector Current (I_{C1}, I_{C2}) | 200 mA |
| Timing Capacitor (C_T) | 470 pF to 10 μ F |
| Timing Resistor (R_T) | 1.8 k Ω to 500 k Ω |
| Oscillator Frequency (f_{OSC}) | 1.0 kHz to 300 kHz |

LM494

Electrical Characteristics $T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ for the LM494C, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ for the LM494I, $V_{CC} = 15V$, $f_{OSC} = 10$ kHz, unless otherwise specified

| Symbol | Parameter | Conditions | | Min | Typ | Max | Units |
|---------------------------|--|---|--------------------------------|------|------|-----------------|-------|
| REFERENCE SECTION | | | | | | | |
| V _{REF} | Reference Voltage (Note 3) | I _{REF} = 1.0 mA | | 4.75 | 5.0 | 5.25 | V |
| Reg _{LINE} | Line Regulation of Reference Voltage | 7.0V ≤ V _{CC} ≤ 40V | | | 2.0 | 25 | mV |
| TCV _{REF} | Temperature Coefficient of Reference Voltage | 0°C ≤ T _A ≤ 70°C | | | 0.01 | 0.03 | %/°C |
| Reg _{LOAD} | Load Regulation of Reference Voltage | 1.0 mA ≤ I _{REF} ≤ 10 mA | | | 1.0 | 15 | mV |
| I _{OS} | Output Short Circuit Current | V _{REF} = 0V | 0°C ≤ T _A ≤ +70°C | 10 | 35 | 50 | mA |
| | | | −40°C ≤ T _A ≤ +85°C | | 35 | | |
| OSCILLATOR SECTION | | | | | | | |
| f _{OSC} | Oscillator Frequency (Figure 10) | C _T = 0.01 μF, R _T = 12 kΩ | | | 10 | | kHz |
| Δf _{OSC} | Oscillator Frequency Change | C _T = 0.01 μF, R _T = 12 kΩ | 0°C ≤ T _A ≤ +70°C | | | 2.0 | % |
| | | | −40°C ≤ T _A ≤ +85°C | | | 2.0 | |
| DEAD TIME CONTROL SECTION | | | | | | | |
| I _{IB} (DT) | Input Bias Current | V _{CC} = 15V, 0V ≤ V ₄ ≤ 5.25V | | | −2.0 | −10 | μA |
| DC _(Max) | Maximum Duty Cycle, Each Output | V _{CC} = 15V, Lead 4 = 0V, Output Control = V _{REF} | | 45 | | | % |
| V _{TH} (in) | Input Threshold Voltage | Zero Duty Cycle | | | 3.0 | 3.3 | V |
| | | Maximum Duty Cycle | | 0 | | | |
| ERROR AMPLIFIER SECTIONS | | | | | | | |
| V _{IO} | Input Offset Voltage | V ₃ = 2.5V | | | 2.0 | 10 | mV |
| I _{IO} | Input Offset Current | V ₃ = 2.5V | | | 25 | 250 | nA |
| I _{IB} | Input Bias Current | V ₃ = 2.5V | | | 0.2 | 1.0 | μA |
| V _{ICR} | Input Common Mode Voltage Range | 7.0V ≤ V _{CC} ≤ 40V | | −0.3 | | V _{CC} | V |
| A _{VS} | Large Signal Voltage Gain | 0.5V ≤ V ₃ ≤ 3.5V | | 60 | 74 | | dB |
| BW | Bandwidth | | | | 650 | | kHz |

LM494

Electrical Characteristics $T_A = 0^\circ\text{C}$ to $+70^\circ\text{C}$ for the LM494C, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ for the LM494I,
 $V_{CC} = 15\text{V}$, $f_{OSC} = 10\text{ kHz}$, unless otherwise specified (Continued)

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|---|---|---|--|------|------|---------------|
| PWM COMPARATOR SECTION (Figure 9) | | | | | | |
| V_{THI} | Inhibit Threshold Voltage | Zero Duty Cycle | | 4.0 | 4.5 | V |
| I_O^- | Output Sink Current (Note 4) | $0.5\text{V} \leq V_3 \leq 3.5\text{V}$ | -0.2 | -0.6 | | mA |
| I_O^+ | Output Source Current (Note 4) | $0.5\text{V} \leq V_3 \leq 3.5\text{V}$ | 2.0 | | | mA |
| OUTPUT SECTION | | | | | | |
| $V_{CE(sat)}$ | Output Saturation Voltage Common Emitter Configuration (Figure 3) | $V_E = 0\text{V}$, $I_C = 200\text{ mA}$ | $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ | 1.1 | 1.3 | V |
| | Emitter Follower Configuration (Figure 4) | $V_C = 15\text{V}$, $I_E = 200\text{ mA}$ | | 1.5 | 2.5 | |
| $I_{C(off)}$ | Collector Off-State Current | $V_{CC} = 40\text{V}$, $V_{CE} = 40\text{V}$ | | 2.0 | 100 | μA |
| $I_{E(off)}$ | Emitter Off-State Current | $V_{CC} = V_C = 40\text{V}$, $V_E = 0$ | $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$, $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$ | | -100 | μA |
| OUTPUT CONTROL (Figure 6) | | | | | | |
| V_{OCL} | Output Control Voltage Required for Single Ended or Parallel Output Operation | | | | 0.4 | V |
| V_{OCH} | Output Control Voltage Required for Push-Pull Operation | | 2.4 | | | V |
| TOTAL DEVICE | | | | | | |
| I_{CC} | Standby Power Supply Current | | | 6.0 | 10 | mA |
| OUTPUT AC CHARACTERISTICS Use Recommended Operating Conditions with $T_A = 25^\circ\text{C}$ | | | | | | |
| t_r | Rise Time of Output Voltage Common Emitter Configuration (Figure 3) | | | 100 | 200 | ns |
| | Emitter Follower Configuration (Figure 4) | | | 100 | 200 | |
| t_f | Fall Time of Output Voltage Common Emitter Configuration (Figure 3) | | | 25 | 100 | ns |
| | Emitter Follower Configuration (Figure 4) | | | 40 | 100 | |

Note 1: $T_J \text{ Max} = 150^\circ\text{C}$ for the Molded DIP, and 175°C for the Ceramic DIP.

Note 2: Ratings apply to ambient temperature at 25°C . Above this temperature, derate the 16L-Ceramic DIP at $10\text{ mW}/^\circ\text{C}$, and the 16L-Molded DIP at $8.3\text{ mW}/^\circ\text{C}$.

Note 3: Selected devices with tightened tolerance reference voltage available.

Note 4: These limits apply when the voltage measured at Lead 3 is within the range specified.

Functional Description

The basic oscillator (switching) frequency is controlled by an external resistor (R_T) and capacitor (C_T). The relationship between the values of R_T , C_T and frequency is shown in *Figure 10*.

The level of the sawtooth wave form is compared with an error voltage by the pulse width modulated comparator. The output of the PWM Comparator directs the pulse steering flip-flop and the output control logic.

The error voltage is generated by the error amplifier. The error amplifier boosts the voltage difference between the output and the 5.0V internal reference. See *Figure 7* for error amp sensing techniques. The second error amp is typically used to implement current-limiting.

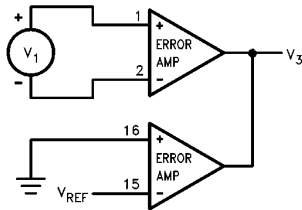
The output control logic selects either push-pull or single-ended operation of the output transistors (see *Figure 6*).

The dead time control prevents on-state overlap of the output transistors as can be seen in *Figure 5*. The dead time is approximately 3.0% or 5.0% of the total period if the dead time control is grounded. This dead time can be increased by connecting the dead time control to a voltage up to 5.0V.

The frequency response of the error amps (*Figure 11*) can be modified by using external resistors and capacitors. These components are typically connected between the compensation terminal and the inverting input of the error amps.

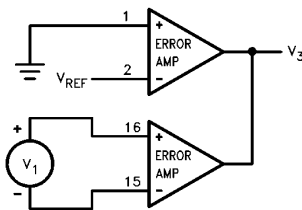
The switching frequency of two or more LM494 circuits can be synchronized. The timing capacitor, C_T , is connected as shown in *Figure 8*. Charging current is provided by the master circuit. Discharging is through all the circuits slaved to the master. R_T is required only for the master circuit.

Test Circuits



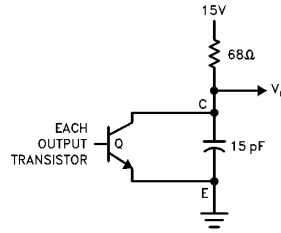
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FIGURE 1. Error Amplifier Test Circuit

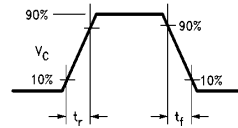


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FIGURE 2. Current Limit Sense Amplifier Test Circuit

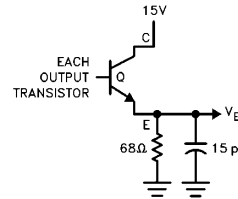


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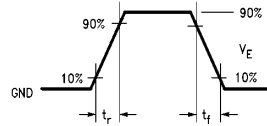


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FIGURE 3. Common Emitter Configuration Test Circuit and Waveform

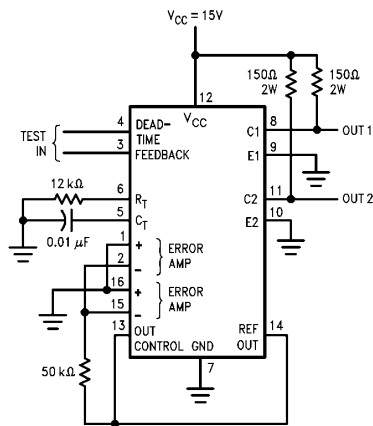


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FIGURE 4. Emitter Follower Configuration Test Circuit and Waveform



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FIGURE 5. Dead Time and Feedback Control Test Circuit

Typical Applications

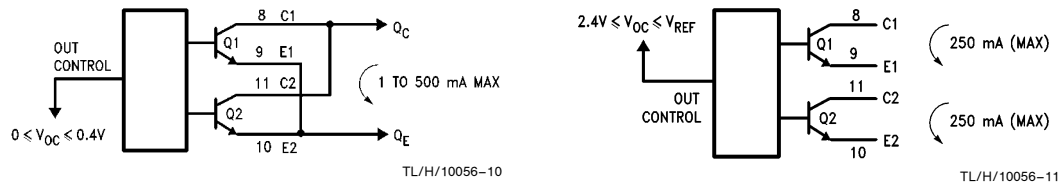


FIGURE 6. Output Connections for Single Ended and Push-Pull Configurations

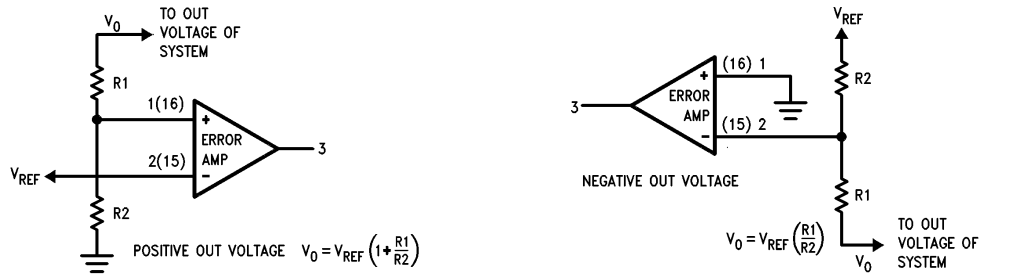


FIGURE 7. Error Amplifier Sensing Techniques

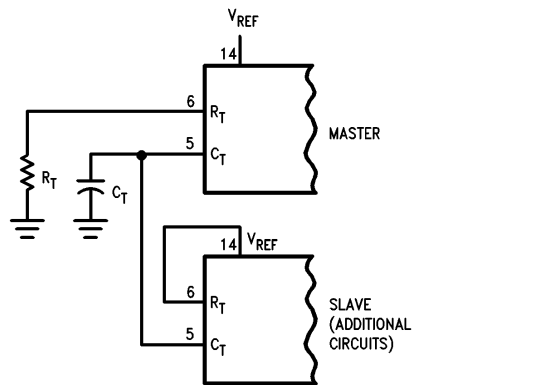


FIGURE 8. Slaving Two or More Control Circuits

Typical Applications (Continued)

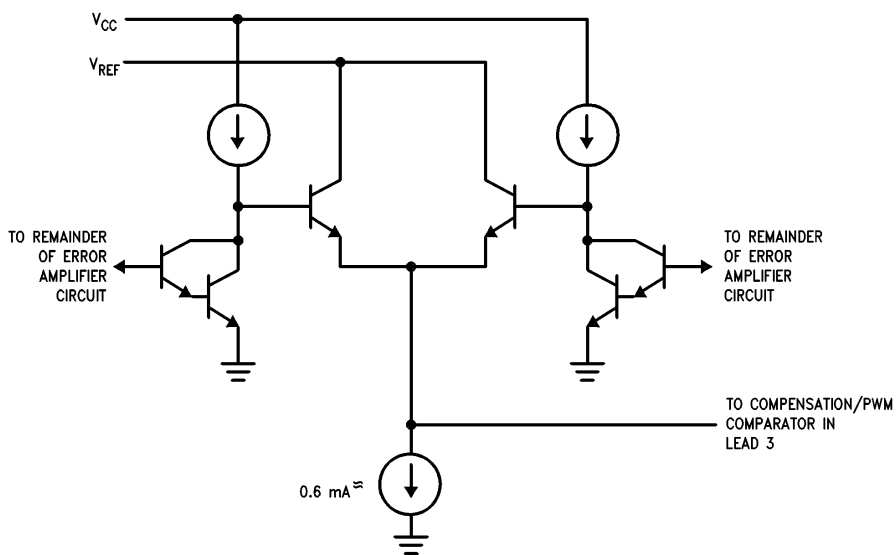


FIGURE 9. Error Amplifier and Current Limit Sense Amplifier Output Circuits

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Typical Performance Characteristics

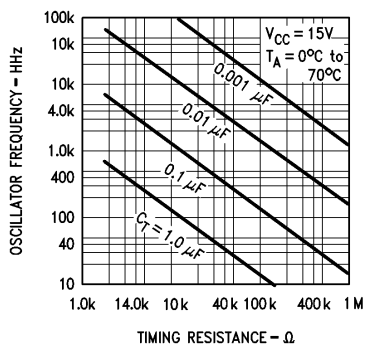


FIGURE 10. Oscillator Frequency vs Timing Resistance

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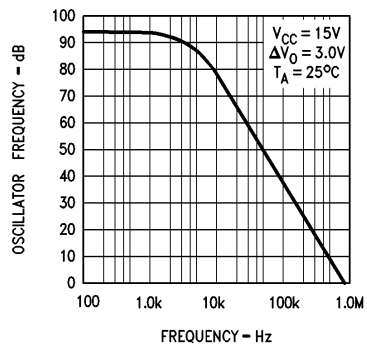
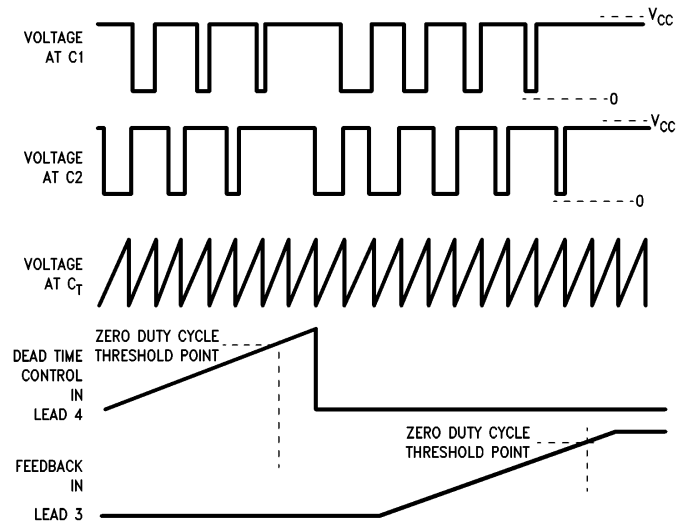


FIGURE 11. Amplifier Voltage Gain vs Frequency

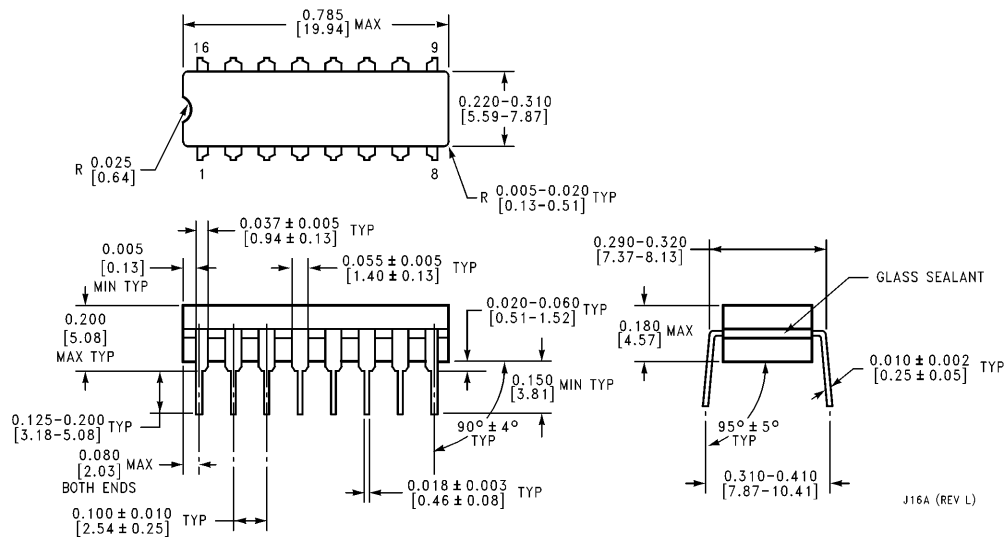
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Voltage Waveforms



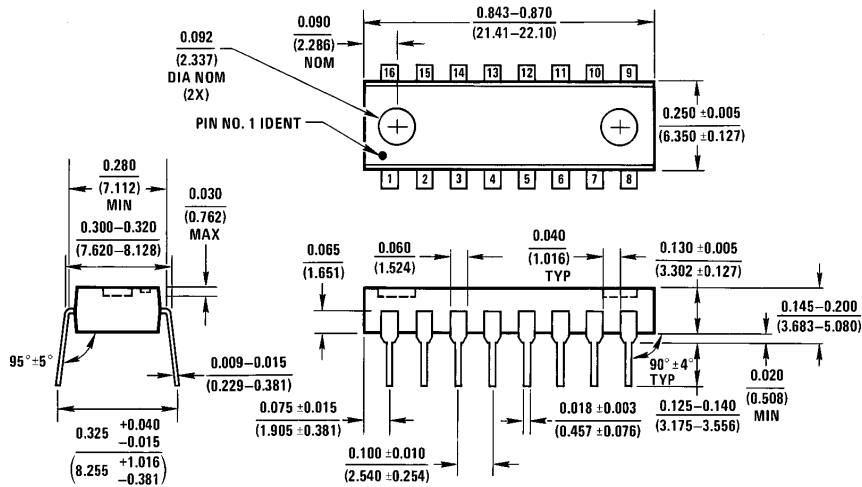
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Physical Dimensions inches (millimeters)



16-Lead Ceramic Dual-In-Line Package (J)
Order Number LM494CJ
NS Package Number J16A

J16A (REV L)

Physical Dimensions inches (millimeters) (Continued)

N16A (REV E)

16-Lead Molded Dual-In-Line Package (N)
Order Number LM494CN or LM494IN
NS Package Number N16A

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